50V, 500mA, Low-IQ 30µA Low-Dropout Linear Regulator with Enable

DESCRIPTION

The TQL851CSV33 is a high-performance low dropout linear regulator for 3.3V with input range of 3V to 50V and low quiescent 30 μ A. TQL851CSV33 provides 2% output voltage accuracy and 500mA maximum driving current and is suitable for automotive or other supply systems. TQL851CSV33 just requires one small ceramic capacitor of 1 μ F to exhibit fast regulation and good stability. And it shows very low dropout voltage with typical 60mV in 100mA-load and 150mV in 250mAload. The start operating voltage is 3V which is suitable to cranking condition of automotive system.

The device has an enable function to switch ON and OFF for power dissipation. And other protection functions such as thermal-shutdown and current-limit are against immediate damage.

FEATURES

- AEC-Q100 qualified with the following results:
 - Device temperature grade 1: -40°C to 125°C
 - Device HBM ESD classification level H2
 - Device CDM ESD classification level C3
- 3V to 50V Input Voltage Range
- 3.3V Fixed Output Voltage
- Typical 60mV @100mA Low Dropout Voltage
- 500mA Output Current
- Typical 30µA Low Quiescent Current
- Typical ±2% Output Voltage Accuracy
- 1µF Ceramic Output Stable Capacitor
- Output Current Limit
- Over Temperature Protection

5. NC

6. NC

7. NC

8. OUT

- RoHS Compliant
- Halogen-Free according to IEC 61249-2-21

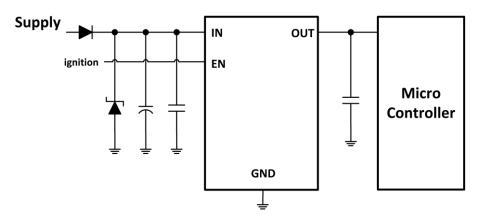
APPLICATION

- Automotive Power Supply Systems
- General Power Supply applications



Notes: Moisture sensitivity level: level 3. Per J-STD-020

TYPICAL APPLICATION CIRCUIT









ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified) (Note 1)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Power Supply Pin	VIN	55	V	
EN Voltage to GND	VEN	-0.3 to 55	V	
OUT/RO/WDO Voltage to GND	V _{OUT} /V _{RO/WDO}	-0.3 to 7	V	
WDI/RTH Voltage to GND	Vwdi/Vrth	-0.3 to 7	V	
Junction Temperature Range	TJ	-40 to +150	°C	
Storage Temperature Range	T _{STG}	-55 to +150	°C	
ESD Rating (Human Body Model) (Note 2)	НВМ	±2	kV	
ESD Rating (Charged Device Model)	CDM	±1	kV	

THERMAL PERFORMANCE					
PARAMETER	SYMBOL	ТҮР	UNIT		
Junction to Case Thermal Resistance	Rejc	12	°C/W		
Junction to Ambient Thermal Resistance	Reja	50	°C/W		

Notes: The thermal data is based on the PCB JESD 51-3 at natural convection on 1s0p board with 1 copper layer (1 x 70µm Cu) and with 300mm² heatsink area on PCB

RECOMMENDED OPERATING CONDITIONS (Note 3)				
PARAMETER	SYMBOL	CONDITIONS	UNIT	
Power Supply Pin	Vin	$V_{OUT}+V_{dr}$ to 50	V	
Extended Power Supply Pin	V _{IN,ext}	3 to 50	V	
EN Voltage to GND	V _{EN}	0 to 50	V	
Output Stable Capacitor	Соит	≧1	μF	
ESR of Output Capacitor	ESR	≦100	Ω	
Operating Junction Temperature Range	TJ	-40 to +150	°C	
Operating Ambient Temperature Range	Тора	-40 to +125	°C	

ELECTRICAL SPECIFICATIONS ($V_{IN} = 13.5V$, $T_J = -40$ to $150^{\circ}C$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	ТҮР	MAX	UNIT
Supply Voltage						
Output Voltage	0.05mA < I _{OUT} < 500mA 4.23V < V _{IN} < 28V	Vouт	3.23	3.3	3.37	V
Output Voltage	0.05mA < I _{OUT} < 200mA 3.72V < V _{IN} < 40V	Vout	3.23	3.3	3.37	V
Start-up Slew-rate	$V_{IN} > 18V/ms$ $C_{OUT} = 1\mu F$ $0.33V < V_{OUT} < 2.97V$	dV₀u⊤/dt		35		V/ms
Current Limit	0V < V _{OUT} < 3.1V	Itim		650		mA
Load Regulation	$I_{OUT} = 0.05$ to 500mA $V_{IN} = 6V$	ΔVout,io	-20	-1.5	5	mV



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ELECTRICAL SPECIFICATIONS (VIN = 13.5V, TJ = -40 to 150°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	ТҮР	MAX	UNIT
Supply Voltage						•
Line Regulation	V _{IN} = 8 to 32V I _{OUT} = 5mA	ΔV _{OUT,li}	-15	0	15	mV
Dropout Voltage (Vdr=VIN-VOUT)	I _{OUT} = 250mA	Vdr		150	425	mV
Dropout Voltage (Vdr=VIN-VOUT)	Iout = 100mA	Vdr		60	170	mV
Power Supply Ripple Rejection	f = 100Hz, V = 0.5Vpp	PSRR		59		dB
Thermal Shutdown Threshold (Note 4)		T _{th}	151		200	°C
Thermal Shutdown Hysteresis (Note 4)		T _{hy}		30		°C
Current Consumption						
Standby Current (Io=IIN)	$V_{EN} = 0V, T_J < 105^{\circ}C$	I _{O,st}		1.3	5	μA
Standby Current (I _O =I _{IN})	$V_{EN} = 0.4V, T_J < 125^{\circ}C$	I _{O,st}			8	μA
Quiescent Current (Io=IIN-IOUT)	Iout = 0.05mA, TJ = 25°C	lo		30	40	μA
Quiescent Current (Io=IIN-IOUT)	Iout = 0.05mA, TJ < 125°C	lo		45	60	μA
Enable						
High Level Input Voltage		Venh	2			V
Low Level Input Voltage	$V_{OUT} \leq 0.1V$	V _{ENL}			0.8	V
Threshold Hysteresis		V _{ENHy}	100			mV
EN Input Current	V _{EN} = 3.3V	I _{EN}			3.5	μA
EN Input Current	$V_{EN} \leq 18V$	I _{EN}			22	μA
EN Pull-down Resistor		R _{EN}	0.95	1.5	2.6	MΩ

Note:

 Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

- 2. Devices are ESD sensitive. Handing precaution recommended.
- 3. The device is not guaranteed to function outside its operating conditions.

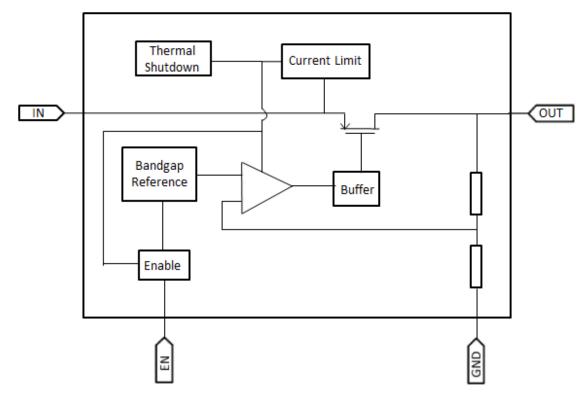
4. Guaranteed by design.

ORDERING INFORMATION

ORDERING CODE	PACKAGE	PACKING
TQL851CSV33 RLG	SOP-8EP	2,500pcs / 13" Reel



BLOCK DIAGRAM



PIN DESCRIPTION

PIN NO.	NAME	FUNCTION
1	IN	Power supply pin for system
2	EN	Enable system function
3	NC	No connect
4	GND	Ground
5	NC	No connect
6	NC	No connect
7	NC	No connect
8	OUT	Output supply voltage
Pad		Connect to GND



APPLICATION INFORMATION

TQL851CSV33 is a high-performance low dropout voltage regulator. The device operates with a wide input voltage from 3V to 50V and up to 500mA of output current. It also provides a high accuracy output voltage for $\pm 2\%$ in all the load and line regulation.

<u>Enable</u>

The EN pin is high voltage tolerant pin. High input enables the device ON and low is disable which can be connected to microcontroller or digital control system. It can be connected to input power pin directly.

Thermal Shutdown (TSD)

Internal 160°C comparator will trigger temperature protection (TSD). TSD will shut down system, until internal temperature back to 130°C.

Current Limit

The TQL851CSV33 features Current Limit function to protect device from damage by excessive power dissipation such as OUT shorted to GND. It limits output current to maintain power dissipation in the safe region.



TYPICAL OPERATING CHARACTERISTICS

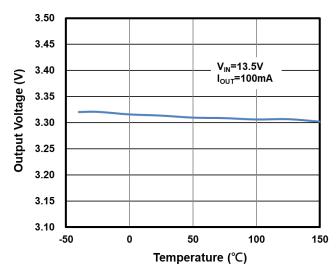


Figure 1. Output Voltage vs. Junction Temperature

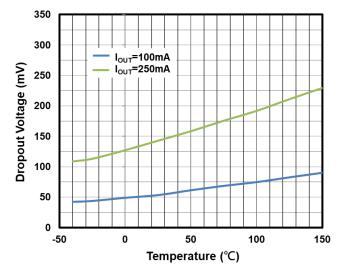


Figure 3. Dropout Voltage vs. Junction Temperature

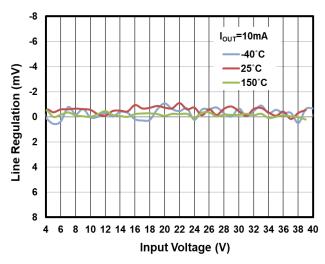


Figure 5. Line Regulation vs. Input Voltage

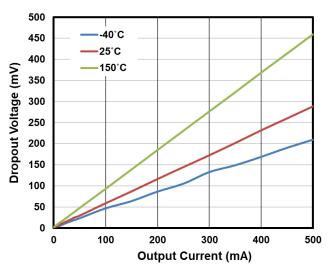


Figure 2. Dropout Voltage vs. Output Current

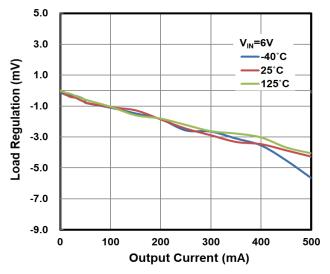


Figure 4. Load Regulation vs. Output Current

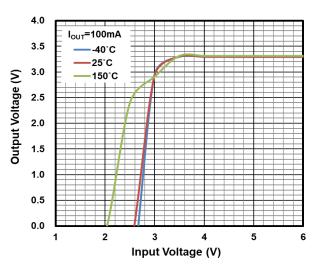


Figure 6. Output Voltage vs. Input Voltage



TYPICAL OPERATING CHARACTERISTICS (CONTINUE)

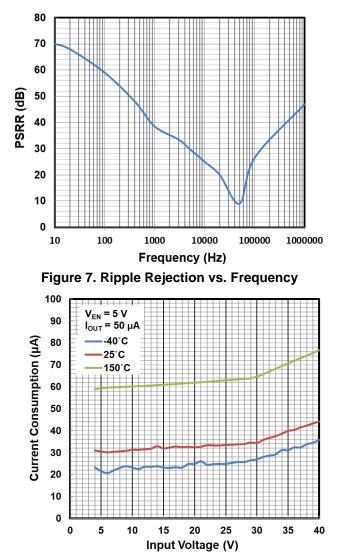
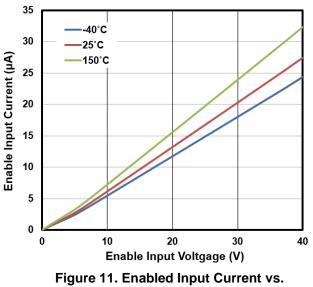


Figure 9. Current Consumption vs. Input Voltage



Enabled Input Voltage

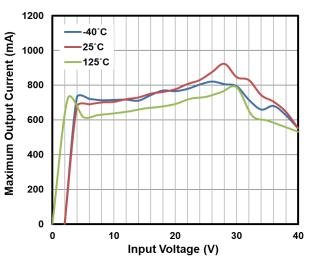


Figure 8. Output Current vs. Input Voltage

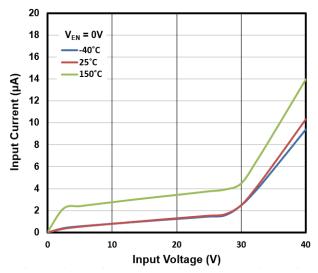


Figure 10. Input Current vs. Input Voltage

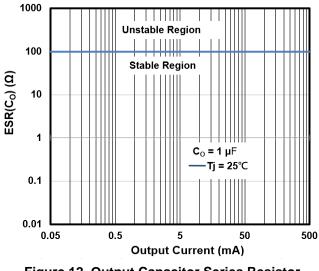


Figure 12. Output Capacitor Series Resistor ESR(C₀) vs. Output Current

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TYPICAL OPERATING CHARACTERISTICS (CONTINUE)

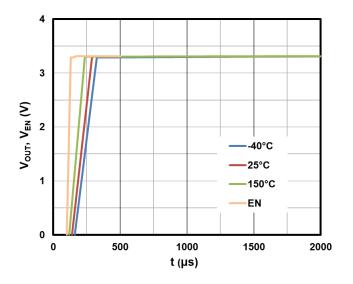
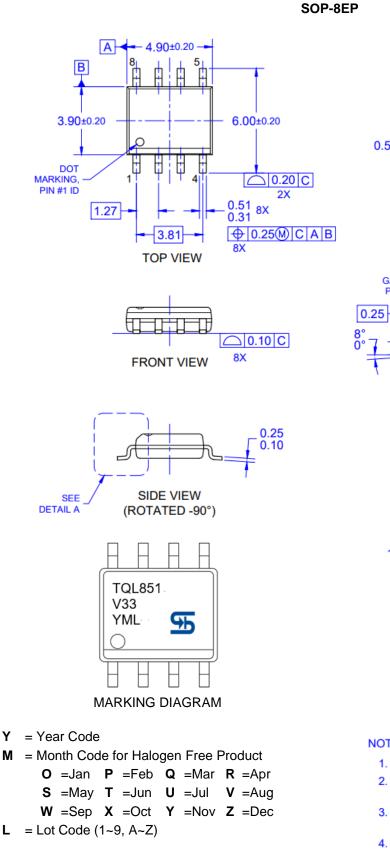
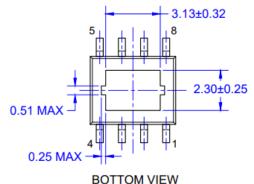


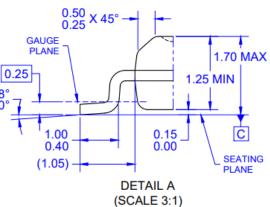
Figure 13. Output Voltage vs. time (EN switched ON)

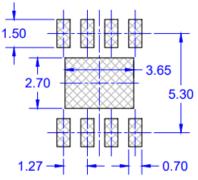


PACKAGE OUTLINE DIMENSIONS









SUGGESTED PAD LAYOUT

NOTES: UNLESS OTHERWISE SPECIFIED

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. PACKAGE OUTLINE REFERENCE: JEDEC MS-012, ISSUE G, VARIATION BA.
- 4. MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 5. DWG NO REF: HQ2SD07-030 REV A.